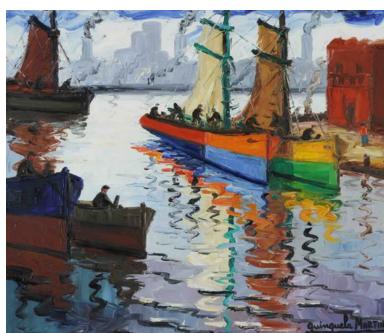
Silicon Photomultiplier characterization on board a satellite in Low Earth Orbit

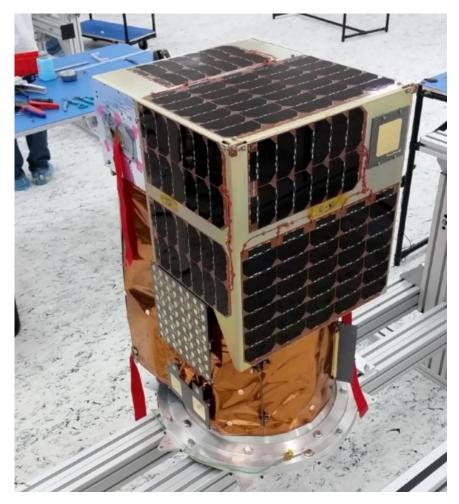
Federico Izraelevitch UNSAM, CNEA, CONICET

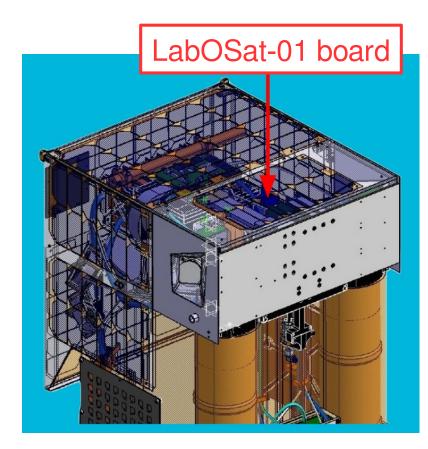
SiPM workshop: from fundamental research to industrial applications Bari Oct-2019



- Objective: novel electronic components and devices \rightarrow Space applications.
- Electronic board to perform experiments on board of satellites.
- Increase the Technology Readiness Level (TRL). \rightarrow Enable usage in future missions.
- Strong partnership with industry: Satellogic.

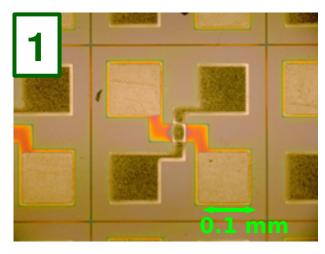
Satellogic spacecraft: Ñu Satellites

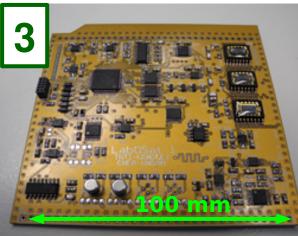


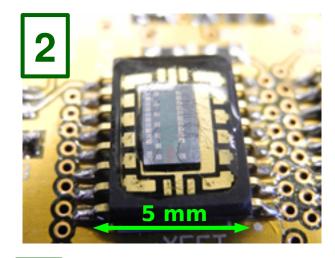


- 40 kg
- 80 cm x 45 cm x 50 cm

The LabOSat Project



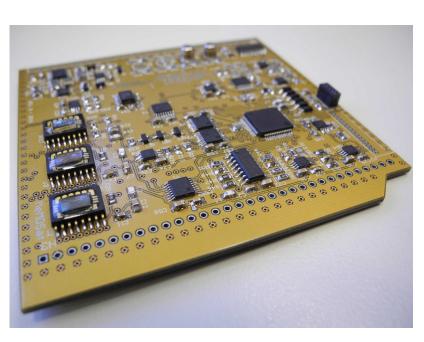








LabOSat-01 board



• Source Measuring Unit (SMU), single channel, multiplexed.

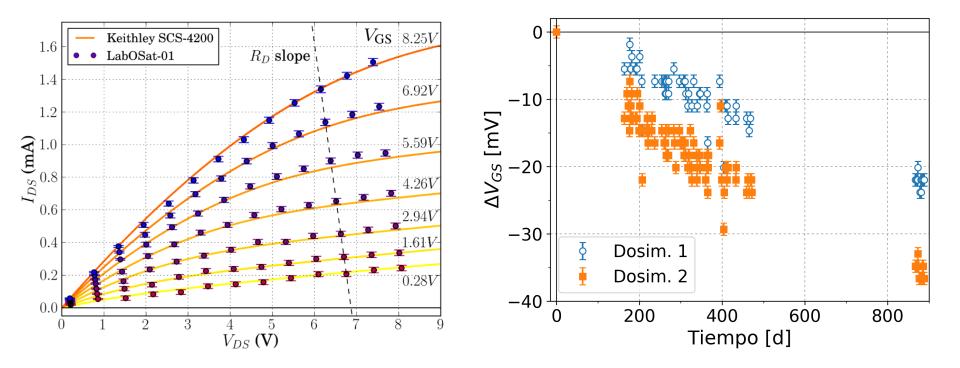
- Dimensions = 10 cm x 10 cm x 1 cm
- Weight = 38 g
- Power cons. < 1 W
- Comm. with host = SPI at 200 kHz
- Space qualification:
 - Thermal under vac:
 - Cycling = $+/-40^{\circ}$ C
 - Steady at 100°C for 7 days
 - Survival shock at +150°C
 - Shaker test
 - Irradiation
 - 10-MeV protons (TandAr)
 - Thermal neutrons (RA-6)

 Successful operation in six satellite missions • At the moment:

 \rightarrow Seven boards in orbit performing experiments.

- Components and devices:
 - Transistors.
 - Resistive switching memories (ReRAM).
 - Sensors.
- Own components, commercial ones, and from collaborators:
 - External groups in Argentina
 - U. Turku (Finland)
 - Nanogune (Spain)
 - INL (Portugal)

MOSFET: Characterization and dosimetry



The LabOSat group (CNEA, CONICET, INTI, UBA, UNSAM)



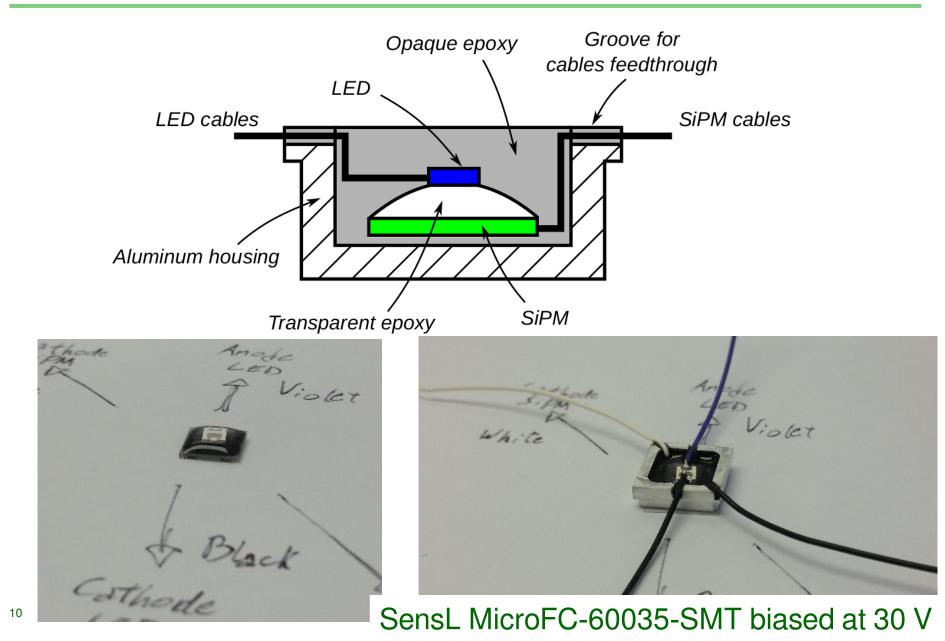
SiPM characterization in DC current mode

- Early 2018: launch opportunity within a year \rightarrow Use the proven LabOSat-01 board
- Objective:

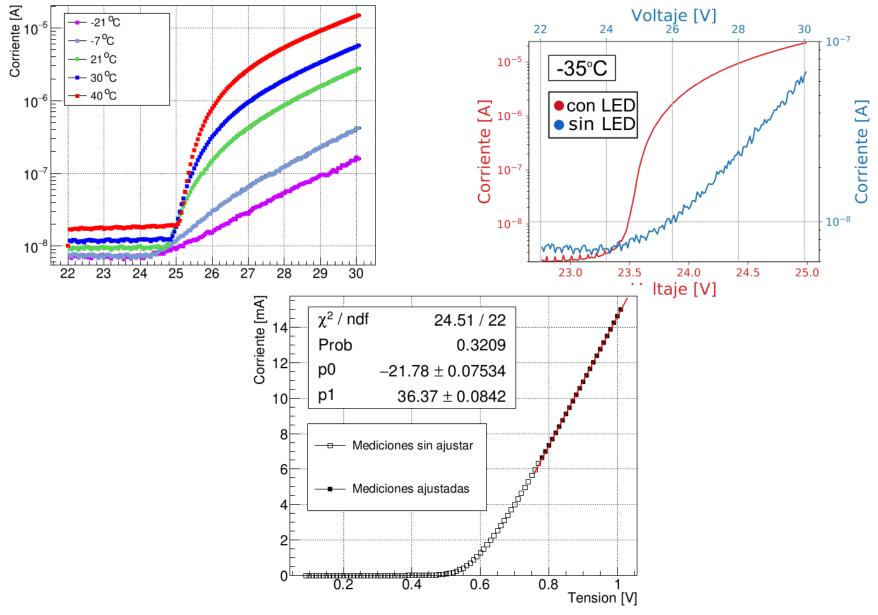
 \rightarrow Validate (learn about) a DC-DC (COTS from LT) for biasing SiPMs

- \rightarrow Bias voltage in Open loop (no temp. correction)
- \rightarrow Measure the DC response of SiPMs at fixed V_{bias}
 - Dark current
 - Under faint DC illumination

SiPM characterization in DC current mode

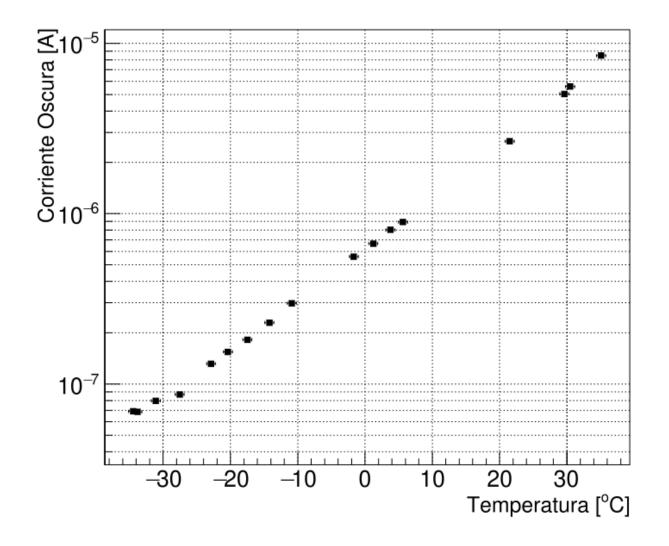


Current-Voltage characterization with benchtop instruments

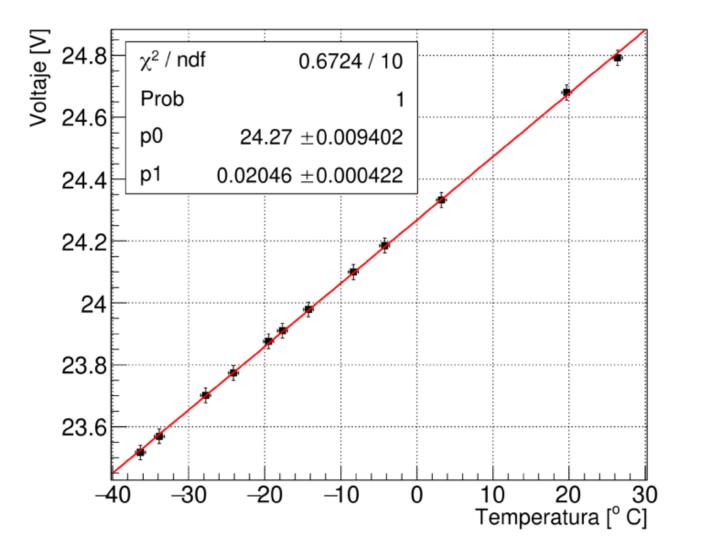


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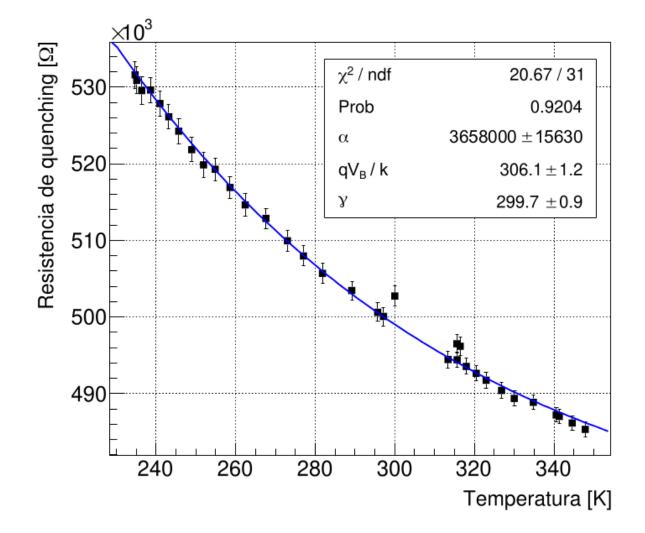
Dark current vs. Temperature



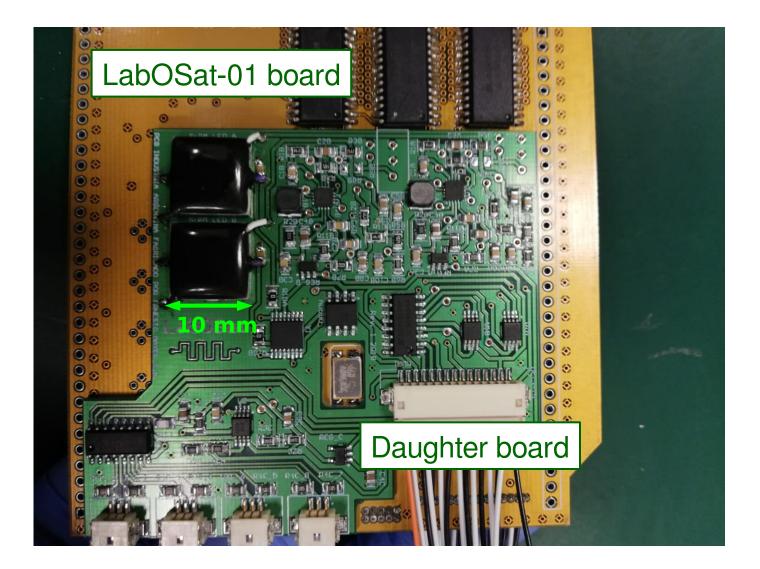
Breakdown voltage vs. Temperature



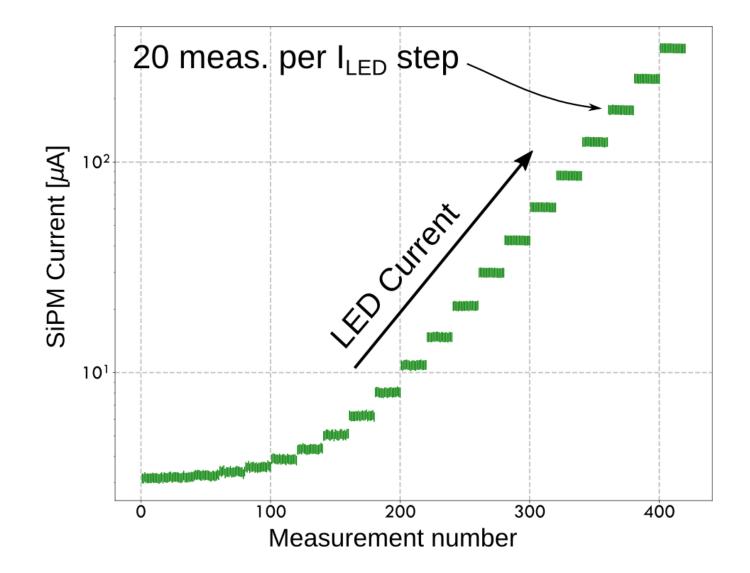
Quenching resistor vs. Temperature



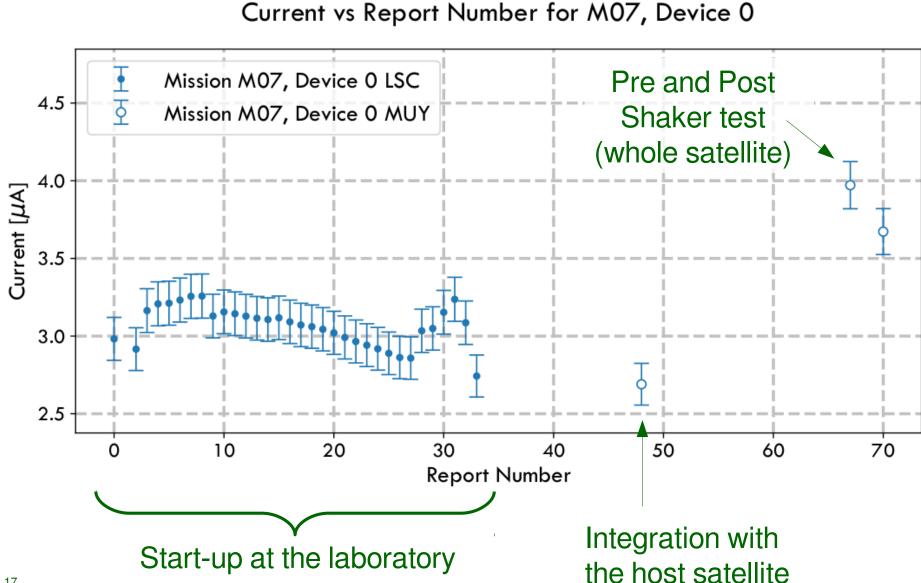
Two SiPM-LED packages in a daughter board

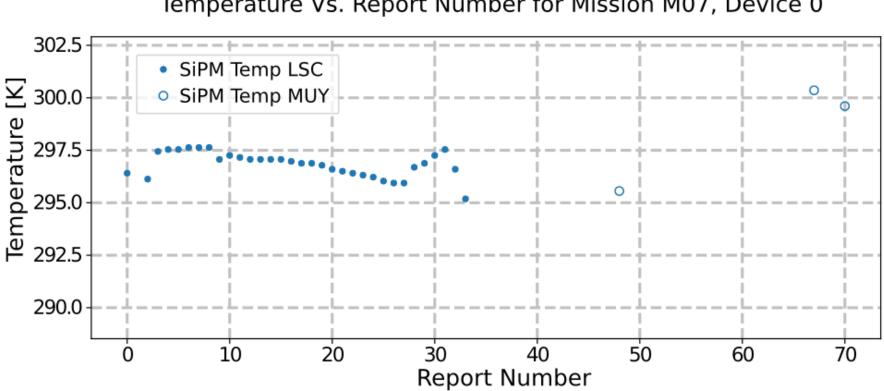


Experiment concept



Dark current vs. Report number

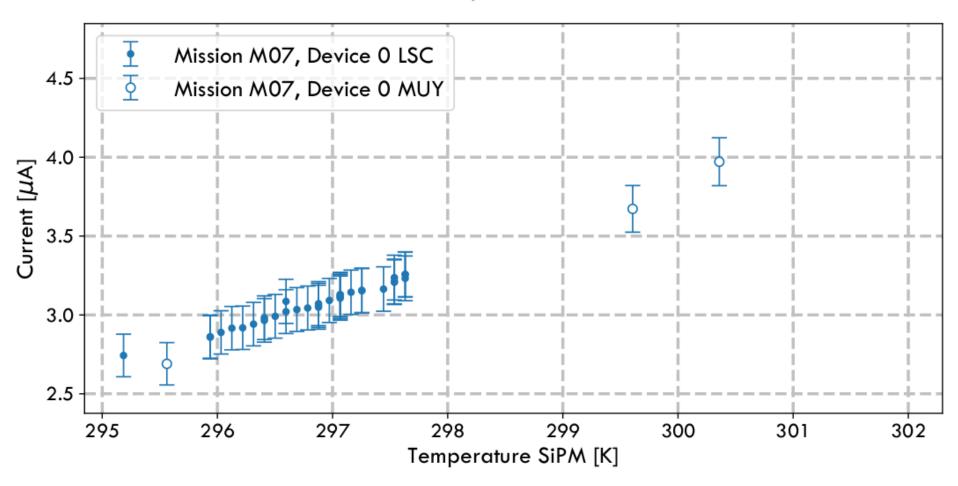




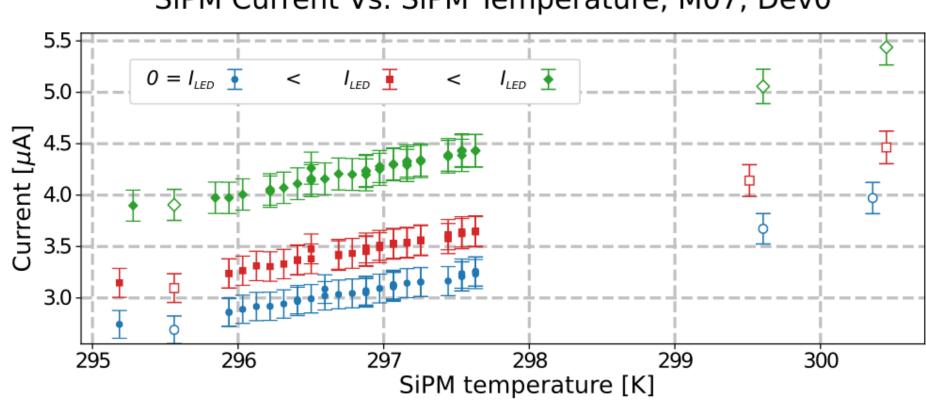
Temperature Vs. Report Number for Mission M07, Device 0

Dark current vs. Temperature

Current vs SiPM Temperature for M07, Device 0



SiPM current for different LED illuminations vs. Temperature

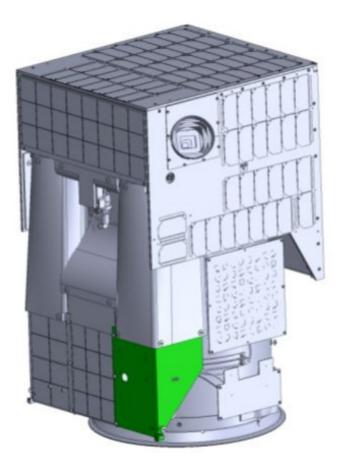


SiPM Current Vs. SiPM Temperature, M07, Dev0

- Launch was expected on Q3 2019 \rightarrow Delayed until Nov-2019
- All the data analysis pipeline done \rightarrow Plots update automatically with new Reports from LEO

LabOSat Project: outlook

- Access to a Secondary Payload Bay
 - Vol ~ 2 liter
 - Mass ~ 1 kg
 - Nadir FoV
- Currently under development:
 - On-board Computer on PC/104
 - Instrument based on 1 or 2 SiPMs in photon counting mode
 - \rightarrow Objective: measure photon flux from different sources



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